

Data Sheet

## May 21, 2008

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FN6337.3
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## 4.5MHz, Single Dual and Quad Precision Rail-to-Rail Input-Output (RRIO) Op Amps with Very Low Input Bias Current

The ISL28148, ISL28248 and ISL28448 are 4.5MHz low-power single, dual and quad operational amplifiers. The parts are optimized for single supply operation from 2.4V to 5.5V, allowing operation from one lithium cell or two Ni-Cd batteries.

The single, dual and quad feature an Input Range Enhancement Circuit (IREC) which enables them to maintain CMRR performance for input voltages greater than the positive supply. The input signal is capable of swinging 0.25V above the positive supply and to 100mV below the negative supply with only a slight degradation of the CMRR performance. The output operation is rail-to-rail.

The parts draw minimal supply current (900 $\mu$ A per amplifier) while meeting excellent DC accuracy, AC performance, noise and output drive specifications. The ISL28148 features an enable pin that can be used to turn the device off and reduce the supply current to a maximum of 16 $\mu$ A. Operation is guaranteed over -40°C to +125°C temperature range.

## Features

- 4.5MHz gain bandwidth product
- 900µA supply current (per amplifier)
- 1.8mV maximum offset voltage
- 1pA typical input bias current
- Down to 2.4V single supply operation
- Rail-to-rail input and output
- Enable pin (ISL28148 SOT-23 package only)
- -40°C to +125°C operation
- Pb-free (RoHS compliant)

### Applications

- Low-end audio
- 4mA to 20mA current loops
- Medical devices
- Sensor amplifiers
- ADC buffers
- DAC output amplifiers

## **Ordering Information**

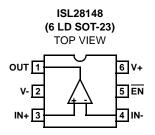
PART NUMBER	PART MARKING	PACKAGE (Pb-Free)	PKG. DWG. #
ISL28148FHZ-T7* (Note 1)	GABT	6 Ld SOT-23 (Tape and Reel)	MDP0038
ISL28148FHZ-T7A* (Note 1)	GABT	6 Ld SOT-23 (Tape and Reel)	MDP0038
ISL28148FIZ-T7 (Note 2)	178Z	6 Ld WLCSP (1.5mmx1.0mm)	W3x2.6C
ISL28248FBZ (Note 1)	28248BZ	8 Ld SOIC	MDP0027
ISL28248FBZ-T7* (Note 1)	28248BZ	8 Ld SOIC (Tape and Reel)	MDP0027
ISL28248FUZ (Note 1)	8248Z	8 Ld MSOP	MDP0043
ISL28248FUZ-T7* (Note 1)	8248Z	8 Ld MSOP (Tape and Reel)	MDP0043
Coming Soon, ISL28448FVZ (Note 1)	MXZ	14 Ld TSSOP	M14.173
Coming Soon, ISL28448FVZ-T7* (Note 1)	MXZ	14 Ld TSSOP (Tape and Reel)	M14.173

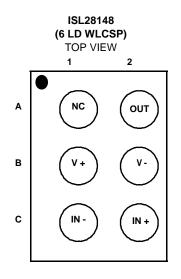
\*Please refer to TB347 for details on reel specifications. NOTES:

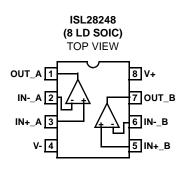
 These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

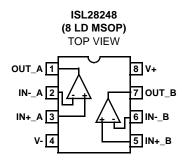
 These Intersil Pb-free WLCSP and BGA packaged products products employ special Pb-free material sets; molding compounds/die attach materials and SnAgCu - e1 solder ball terminals, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free WLCSP and BGA packaged products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

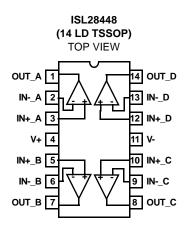












#### Absolute Maximum Ratings (T<sub>A</sub> = +25°C)

Supply Voltage    5.75V      Supply Turn On Voltage Slew Rate    1V/µs      Differential Input Current    5mA      Differential Input Voltage    0.5V      Input Voltage    0.5V      ESD Rating    5
Human Body Model

#### **Thermal Information**

Thermal Resistance (Typical, Note 3)	θ <sub>JA</sub> (°C/W)
6 Ld SOT-23 Package	230
6 Ld WLCSP Package	130
8 Ld SO Package	125
8 Ld MSOP Package	175
14 Ld TSSOP Package	115
Ambient Operating Temperature Range40°	C to +125°C
Storage Temperature Range65°	C to +150°C
Operating Junction Temperature	+125°C
Pb-free reflow profilese	e link below
http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTE:

3.  $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore:  $T_J = T_C = T_A$ 

# **Electrical Specifications** $V_{+} = 5V, V_{-} = 0V, V_{CM} = 2.5V, R_{L} = Open, T_{A} = +25^{\circ}C$ unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +125°C. Temperature data established by characterization.

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 4)	ТҮР	MAX (Note 4)	UNIT
V <sub>OS</sub>	Input Offset Voltage	ISL28148	-1.8 -2	0	1.8 <b>2</b>	mV
		ISL28148 CSP package	-1.0 - <b>1.2</b>	-0.1	1.0 <b>1.2</b>	
		ISL28248 and ISL28448	-1.8 - <b>2.8</b>	0	1.8 <b>2.8</b>	
$\frac{\Delta V_{OS}}{\Delta T}$	Input Offset Voltage vs Temperature			0.03		µV/°C
I <sub>OS</sub>	Input Offset Current	$T_A = -40^{\circ}C$ to +85°C	-35 <b>-80</b>	±5	35 <b>80</b>	pА
IB	Input Bias Current	$T_A = -40^{\circ}C$ to +85°C	-30 <b>-80</b>	±1	30 <b>80</b>	pА
		CSP package T <sub>A</sub> = -40°C to +85°C	-40 <b>-90</b>	±1	30 <b>80</b>	
CMIR	Common-Mode Voltage Range	Guaranteed by CMRR	0		5	V
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 0V \text{ to } 5V$	75 <b>70</b>	98		dB
PSRR	Power Supply Rejection Ratio	V <sub>+</sub> = 2.4V to 5.5V	80 <b>75</b>	98		dB
A <sub>VOL</sub>	Large Signal Voltage Gain	$V_{O}$ = 0.5V to 4.5V, $R_{L}$ = 100k $\Omega$ to $V_{CM}$	200 <b>150</b>	580		V/mV
		$V_{O}$ = 0.5V to 4.5V, $R_{L}$ = 1k $\Omega$ to $V_{CM}$		50		V/mV
V <sub>OUT</sub>	Maximum Output Voltage Swing	Output low, $R_L = 100 k\Omega$ to $V_{CM}$		3	6 <b>8</b>	mV
		Output low, $R_L = 1k\Omega$ to $V_{CM}$		50	70 <b>110</b>	mV
		Output high, $R_L = 100 k\Omega$ to $V_{CM}$	4.994 <b>4.99</b>	4.998		V
		Output high, $R_L = 1k\Omega$ to $V_{CM}$	4.93 <b>4.89</b>	4.95		V
I <sub>S,ON</sub>	Quiescent Supply Current, Enabled	Per Amplifier		0.9	1.25 <b>1.4</b>	mA

### **Electrical Specifications**

V+ = 5V, V- = 0V,  $V_{CM}$  = 2.5V,  $R_L$  = Open,  $T_A$  = +25°C unless otherwise specified. Boldface limits apply over the operating temperature range, -40°C to +125°C. Temperature data established by characterization. (Continued)

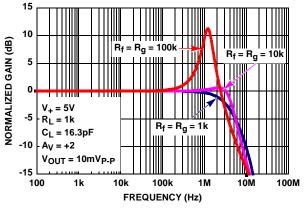
PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 4)	ТҮР	MAX (Note 4)	UNIT
I <sub>S,OFF</sub>	Quiescent Supply Current, Disabled	ISL28148 SOT-23 package only		10	14 <b>16</b>	μA
I <sub>O</sub> +	Short-Circuit Output Source Current	$R_L = 10\Omega$ to $V_{CM}$	48 <b>45</b>	75		mA
I <sub>O</sub> -	Short-Circuit Output Sink Current	$R_L = 10\Omega$ to $V_{CM}$		-68	-48 <b>-45</b>	mA
V <sub>SUPPLY</sub>	Supply Operating Range	V+ to V-	2.4		5.5	V
V <sub>ENH</sub>	EN Pin High Level	ISL28148 SOT-23 package only	2			V
V <sub>ENL</sub>	EN Pin Low Level	ISL28148 SOT-23 package only			0.8	V
I <sub>ENH</sub>	EN Pin Input High Current	V EN = V+, ISL28148 SOT-23 package only		1	1.5 <b>1.6</b>	μA
I <sub>ENL</sub>	EN Pin Input Low Current	$V \overline{EN} = V$ -, ISL28148 SOT-23 package only		12	25 <b>30</b>	nA
AC SPECIFICAT	TIONS	I	1		1	
GBW	Gain Bandwidth Product			4.5		MHz
Unity Gain Bandwidth	-3dB Bandwidth	$A_V = 1, R_F = 0\Omega, V_{OUT} = 10mV_{P-P}, R_L = 10k\Omega$ to $V_{CM}$		13		MHz
e <sub>N</sub>	Input Noise Voltage Peak-to-Peak	f = 0.1Hz to 10Hz		2		μV <sub>PP</sub>
	Input Noise Voltage Density	f <sub>O</sub> = 1kHz		28		nV <b>/</b> √Hz
i <sub>N</sub>	Input Noise Current Density	f <sub>O</sub> = 1kHz		0.016		pA/√Hz
CMRR @ 60Hz	Input Common Mode Rejection Ratio	$V_{CM} = 1V_{P-P}$ , $R_L = 10k\Omega$ to $V_{CM}$		85		dB
PSRR- @ 120Hz	Power Supply Rejection Ratio (V_)	V <sub>+</sub> , V <sub>-</sub> = ±1.2V and ±2.5V, V <sub>SOURCE</sub> = 1V <sub>P-P</sub> , R <sub>L</sub> = 10kΩ to V <sub>CM</sub>		-82		dB
PSRR+ @ 120Hz	Power Supply Rejection Ratio (V <sub>+</sub> )	$V_+, V = \pm 1.2V$ and $\pm 2.5V$ V <sub>SOURCE</sub> = $1V_{P-P}$ , $R_L = 10k\Omega$ to $V_{CM}$		-100		dB
TRANSIENT RE	SPONSE		r.		4	I
SR	Slew Rate			±4		V/µs
t <sub>r</sub> , t <sub>f</sub> , Large Signal	Rise Time, 10% to 90%, V <sub>OUT</sub>	$A_V$ = +2, $V_{OUT}$ = $3V_{P-P}$ , $R_G$ = $R_F$ = $10k\Omega$ $R_L$ = $10k\Omega$ to $V_{CM}$		530		ns
	Fall Time, 90% to 10%, V <sub>OUT</sub>	$\begin{array}{l} A_V = +2,  V_{OUT} = 3V_{P\text{-}P},  R_G = R_F = 10 \mathrm{k}\Omega \\ R_L = 10 \mathrm{k}\Omega \text{ to } V_{CM} \end{array}$		530		ns
t <sub>r</sub> , t <sub>f</sub> , Small Signal	Rise Time, 10% to 90%, V <sub>OUT</sub>	$A_V = +2$ , $V_{OUT} = 10mV_{P-P}$ , $R_G = R_F = R_L = 10k\Omega$ to $V_{CM}$		50		ns
	Fall Time, 90% to 10%, V <sub>OUT</sub>	$A_V = +2$ , $V_{OUT} = 10mV_{P-P}$ , $R_G = R_F = R_L = 10k\Omega$ to $V_{CM}$		50		ns
tEN	Enable to Output Turn-on Delay Time, 10% EN to 10% V <sub>OUT</sub> , (ISL28148)	$\overline{EN}$ = 5V to 0V, A <sub>V</sub> = +2, R <sub>G</sub> = R <sub>F</sub> = R <sub>L</sub> = 1k to V <sub>CM</sub>		5		μs
	Enable to Output Turn-off Delay Time, 10% EN to 10% V <sub>OUT</sub> , (ISL28148)	$V_{\overline{EN}} = 0V$ to 5V, $A_V = +2$ , $R_G = R_F = R_L = 1k$ to $V_{CM}$		0.2		μs

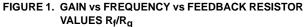
NOTE:

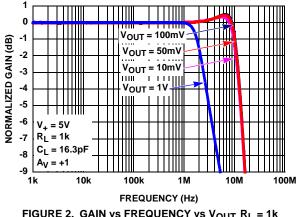
4. Parts are 100% tested at +25°C. Temperature limits established by characterization and are not production tested.

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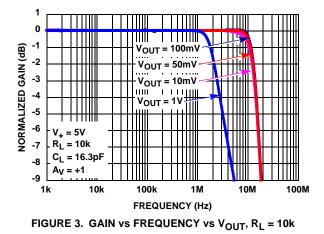
#### Typical Performance Curves V+ = 5V, V- = 0V, V<sub>CM</sub> = 2.5V, R<sub>L</sub> = Open

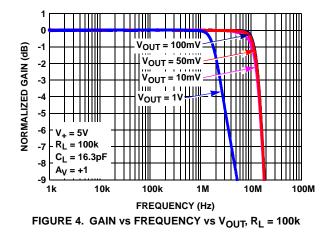


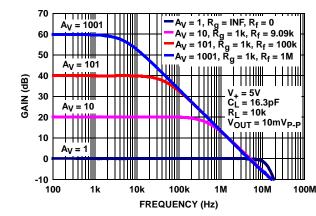




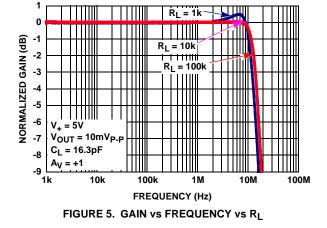












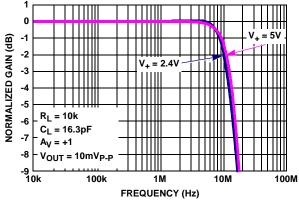
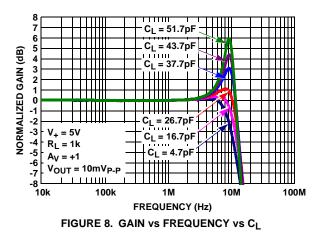
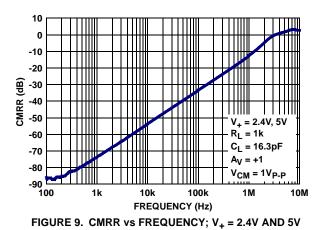
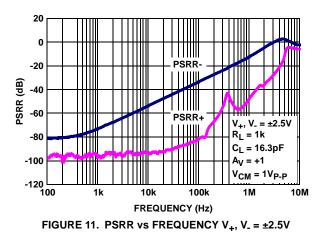
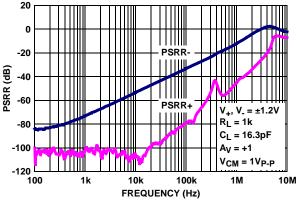


FIGURE 7. GAIN vs FREQUENCY vs SUPPLY VOLTAGE

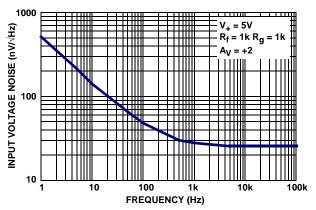


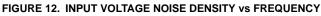


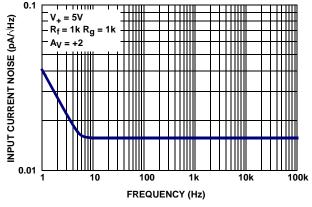














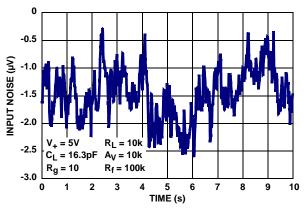


FIGURE 14. INPUT VOLTAGE NOISE 0.1Hz TO 10Hz

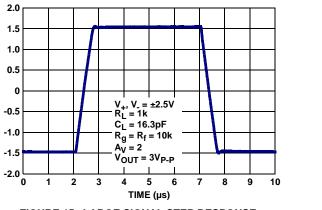


FIGURE 15. LARGE SIGNAL STEP RESPONSE

LARGE SIGNAL (V)

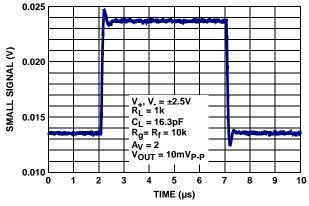


FIGURE 16. SMALL SIGNAL STEP RESPONSE

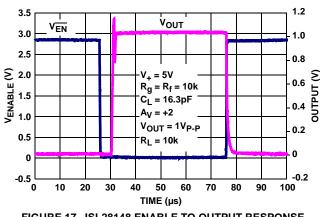
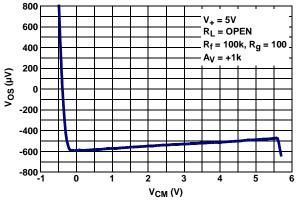


FIGURE 17. ISL28148 ENABLE TO OUTPUT RESPONSE





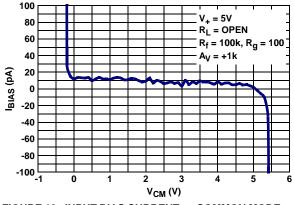


FIGURE 19. INPUT BIAS CURRENT vs COMMON MODE INPUT VOLTAGE

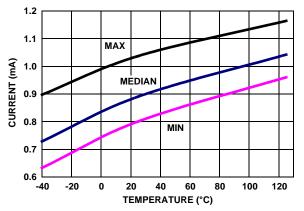


FIGURE 20. SUPPLY CURRENT ENABLED vs TEMPERATURE V\_+, V\_ =  $\pm 2.5V$ 

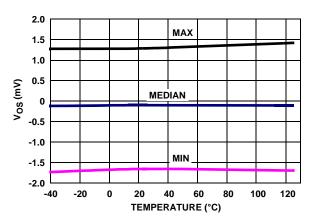


FIGURE 22.  $V_{OS}$  vs TEMPERATURE  $V_{IN}$  = 0V,  $V_+$ ,  $V_-$  = ±2.75V

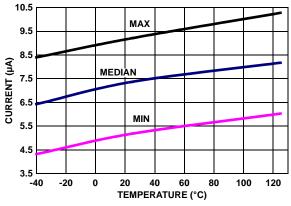
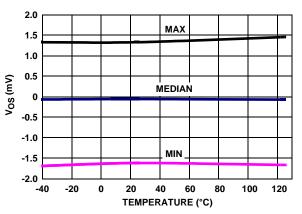


FIGURE 21. SUPPLY CURRENT DISABLED vs TEMPERATURE V<sub>+</sub>, V<sub>-</sub> = ±2.5V





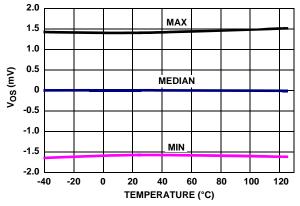


FIGURE 24.  $V_{OS}$  vs TEMPERATURE  $V_{IN}$  = 0V,  $V_+$ ,  $V_-$  = ±1.2V

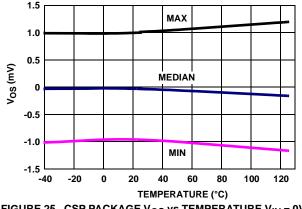


FIGURE 25. CSP PACKAGE V<sub>OS</sub> vs TEMPERATURE V<sub>IN</sub> = 0V, V<sub>+</sub>, V<sub>-</sub> =  $\pm 2.75$ V

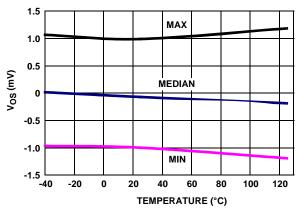


FIGURE 26. CSP PACKAGE V<sub>OS</sub> vs TEMPERATURE V<sub>IN</sub> = 0V, V<sub>+</sub>, V<sub>-</sub> =  $\pm 2.5V$ 

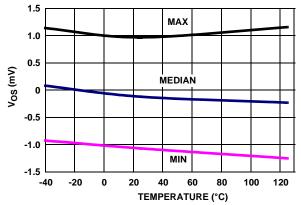
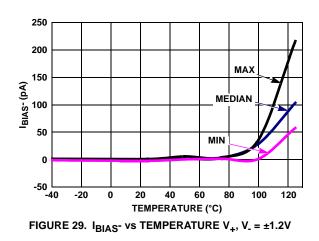
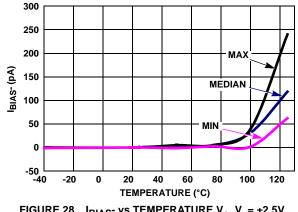
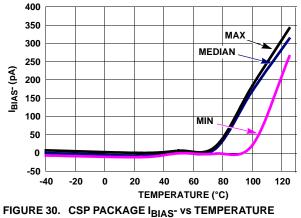
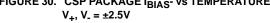


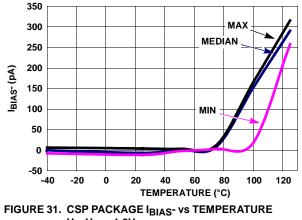
FIGURE 27. CSP PACKAGE V<sub>OS</sub> vs TEMPERATURE V<sub>IN</sub> = 0V,  $V_{+}, V_{-} = \pm 1.2V$ 



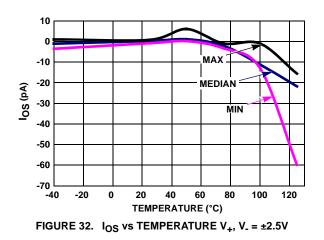


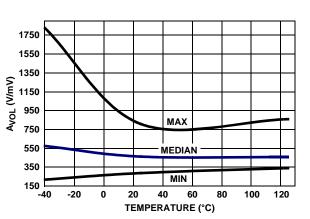














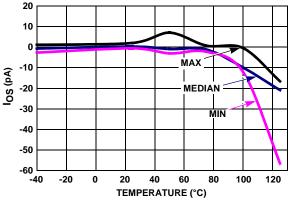
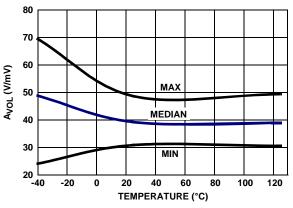
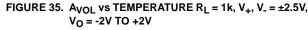


FIGURE 33. I<sub>OS</sub> vs TEMPERATURE V<sub>+</sub>, V<sub>-</sub> = ±1.2V





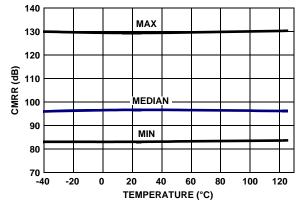


FIGURE 36. CMRR vs TEMPERATURE V<sub>CM</sub> = -2.5V TO +2.5V, V<sub>+</sub>, V<sub>-</sub> =  $\pm 2.5V$ 

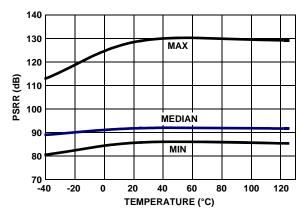


FIGURE 37. PSRR vs TEMPERATURE V+, V = ±1.2V TO ±2.75V

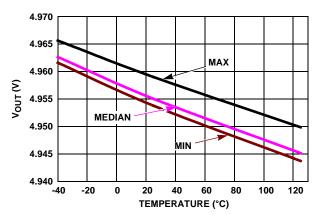


FIGURE 38. V<sub>OUT</sub> HIGH vs TEMPERATURE R<sub>L</sub> = 1k,  $V_+, V_- = \pm 2.5V$ 

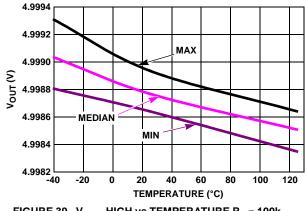
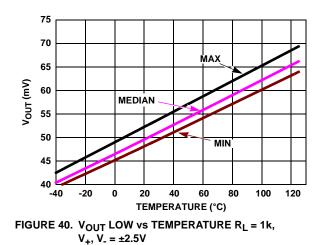
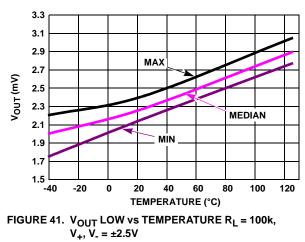
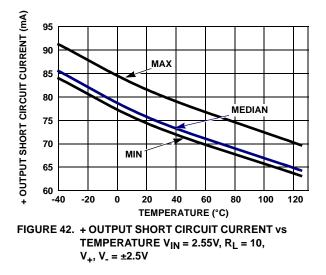
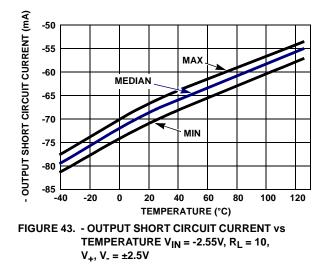


FIGURE 39. V<sub>OUT</sub> HIGH vs TEMPERATURE R<sub>L</sub> = 100k, V<sub>+</sub>, V<sub>-</sub> =  $\pm 2.5$ V









## **Pin Descriptions**

ISL28148 (6 Ld SOT-23)	ISL28148 6 Ld WLCSP	ISL28248 (8 Ld SO) (8 Ld MSOP)	ISL28448 (14 Ld TSSOP)	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
				NC	Not connected	
4	C1	2 (A) 6 (B)	2 (A) 6 (B) 9 (C) 13 (D)	IN- INA INB INC IND	inverting input	
3	C2	3 (A) 5 (B)	3 (A) 5 (B) 10 (C) 12 (D)	IN+ IN+_A IN+_B IN+_C IN+_D	Non-inverting input	(See circuit 1)
2	B2	4	11	V-	Negative supply	V+ C CAPACITIVELY COUPLED ESD CLAMP V- C Circuit 2
1	A2	1 (A) 7 (B)	1 (A) 7 (B) 8 (C) 14 (D)	OUT OUT_A OUT_B OUT_C OUT_D	Output	V+ + V+ OUT + V- Circuit 3
6	B1	8	4	V+	Positive supply	(See circuit 2)

#### Pin Descriptions (Continued)

ISL28148 (6 Ld SOT-23)	ISL28148 6 Ld WLCSP	ISL28248 (8 Ld SO) (8 Ld MSOP)	ISL28448 (14 Ld TSSOP)	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
5			-	ĒN	Chip enable	EN D Circuit 4
	A1			NC	Connect pin to the most Negative Supply	

## **Applications Information**

#### Introduction

The ISL28148, ISL28248 and ISL28448 are single, dual and quad channel CMOS rail-to-rail input, output (RRIO) micropower precision operational amplifiers. The parts are designed to operate from single supply (2.4V to 5.5V) or dual supply ( $\pm$ 1.2V to  $\pm$ 2.75V). The parts have an input common mode range that extends 0.25V above the positive rail and 100mV below the negative supply rail. The output can swing within about 3mV of the supply rails with a 100k $\Omega$  load.

#### Rail-to-Rail Input

Many rail-to-rail input stages use two differential input pairs, a long-tail PNP (or PFET) and an NPN (or NFET). Severe penalties have to be paid for this circuit topology. As the input signal moves from one supply rail to another, the operational amplifier switches from one input pair to the other causing drastic changes in input offset voltage and an undesired change in magnitude and polarity of input offset current.

The parts achieve input rail-to-rail operation without sacrificing important precision specifications and degrading distortion performance. The devices' input offset voltage exhibits a smooth behavior throughout the entire common-mode input range. The input bias current vs the common-mode voltage range gives us an undistorted behavior from typically 100mV below the negative rail and 0.25V higher than the V+ rail.

### Rail-to-Rail Output

A pair of complementary MOS devices are used to achieve the rail-to-rail output swing. The NMOS sinks current to swing the output in the negative direction. The PMOS sources current to swing the output in the positive direction. The devices' with a 100k $\Omega$  load will swing to within 3mV of the positive supply rail and within 3mV of the negative supply rail.

### Results of Over-Driving the Output

Caution should be used when over-driving the output for long periods of time. Over-driving the output can occur in two ways:

- 1. The input voltage times the gain of the amplifier exceeds the supply voltage by a large value or
- 2. The output current required is higher than the output stage can deliver. These conditions can result in a shift in the Input Offset Voltage ( $V_{OS}$ ) as much as 1 $\mu$ V/hr. of exposure under these condition.

#### IN+ and IN- Input Protection

All input terminals have internal ESD protection diodes to both positive and negative supply rails, limiting the input voltage to within one diode beyond the supply rails. They also contain back-to-back diodes across the input terminals ("Pin Descriptions" table - Circuit 1 on page 12). For applications where the input differential voltage is expected to exceed 0.5V, an external series resistor must be used to ensure the input currents never exceed 5mA (Figure 44).

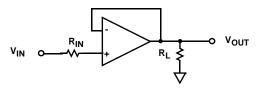


FIGURE 44. INPUT CURRENT LIMITING

#### Enable/Disable Feature

The ISL28148 offers an  $\overline{\text{EN}}$  pin that disables the device when pulled up to at least 2.0V. In the disabled state (output in a high impedance state), the part consumes typically 10µA at room temperature. By disabling the part, multiple ISL28148 parts can be connected together as a MUX. In this configuration, the outputs are tied together in parallel and a channel can be selected by the  $\overline{\text{EN}}$  pin. The loading effects of the feedback resistors of the disabled amplifier must be considered when multiple amplifier outputs are connected together. Note that feed through from the IN+ to IN- pins occurs on any Mux Amp disabled channel where the input differential voltage exceeds 0.5V (e.g., active channel V<sub>OUT</sub> = 1V, while disabled channel V<sub>IN</sub> = GND), so the mux implementation is best suited for small signal applications. If large signals are required, use series IN+ resistors, or large value  $R_F$ , to keep the feed through current low enough to minimize the impact on the active channel. See "Limitations of the Differential Input Protection" on page 14 for more details. The  $\overline{EN}$  pin also has an internal pull-down. If left open, the  $\overline{EN}$  pin will pull to the negative rail and the device will be enabled by default. When not used, the  $\overline{EN}$  pin should either be left floating or connected directly to the V- pin.

### Limitations of the Differential Input Protection

If the input differential voltage is expected to exceed 0.5V, an external current limiting resistor must be used to ensure the input current never exceeds 5mA. For non-inverting unity gain applications the current limiting can be via a series IN+ resistor, or via a feedback resistor of appropriate value. For other gain configurations, the series IN+ resistor is the best choice, unless the feedback ( $R_F$ ) and gain setting ( $R_G$ ) resistors are both sufficiently large to limit the input current to 5mA.

Large differential input voltages can arise from several sources:

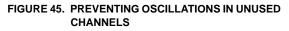
- During open loop (comparator) operation. Used this way, the IN+ and IN- voltages don't track, so differentials arise.
- When the amplifier is disabled but an input signal is still present. An R<sub>L</sub> or R<sub>G</sub> to GND keeps the IN- at GND, while the varying IN+ signal creates a differential voltage. Mux Amp applications are similar, except that the active channel V<sub>OUT</sub> determines the voltage on the IN- terminal.
- When the slew rate of the input pulse is considerably faster than the op amp's slew rate. If the V<sub>OUT</sub> can't keep up with the IN+ signal, a differential voltage results, and visible distortion occurs on the input and output signals. To avoid this issue, keep the input slew rate below  $4.8V/\mu s$ , or use appropriate current limiting resistors.

Large (>2V) differential input voltages can also cause an increase in disabled  $\ensuremath{\mathsf{I}_{CC}}\xspace.$ 

### Using Only One Channel

If the application does not use all channels, then the user must configure the unused channel(s) to prevent them from oscillating. The unused channel(s) will oscillate if the input and output pins are floating. This will result in higher than expected supply currents and possible noise injection into the channel being used. The proper way to prevent this oscillation is to short the output to the negative input and ground the positive input (as shown in Figure 45).





#### Proper Layout Maximizes Performance

To achieve the maximum performance of the high input impedance and low offset voltage, care should be taken in the circuit board layout. The PC board surface must remain clean and free of moisture to avoid leakage currents between adjacent traces. Surface coating of the circuit board will reduce surface moisture and provide a humidity barrier, reducing parasitic resistance on the board. When input leakage current is a concern, the use of guard rings around the amplifier inputs will further reduce leakage currents. Figure 46 shows a guard ring example for a unity gain amplifier that uses the low impedance amplifier output at the same voltage as the high impedance input to eliminate surface leakage. The guard ring does not need to be a specific width, but it should form a continuous loop around both inputs. For further reduction of leakage currents, components can be mounted to the PC board using Teflon standoff insulators.

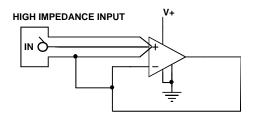


FIGURE 46. GUARD RING EXAMPLE FOR UNITY GAIN AMPLIFIER

#### **Current Limiting**

These devices have no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

#### **Power Dissipation**

It is possible to exceed the +150°C maximum junction temperatures under certain load and power-supply conditions. It is therefore important to calculate the maximum junction temperature ( $T_{JMAX}$ ) for all applications to determine if power supply voltages, load conditions, or package type need to be modified to remain in the safe operating area. These parameters are related in Equation 1:

$$T_{JMAX} = T_{MAX} + (\theta_{JA} x PD_{MAXTOTAL})$$
(EQ. 1)

where:

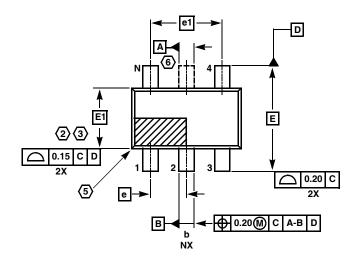
- P<sub>DMAXTOTAL</sub> is the sum of the maximum power dissipation of each amplifier in the package (PD<sub>MAX</sub>)
- PD<sub>MAX</sub> for each amplifier can be calculated as shown in Equation 2:

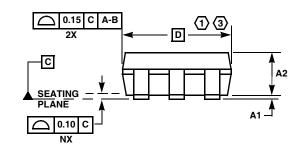
$$PD_{MAX} = 2*V_{S} \times I_{SMAX} + (V_{S} - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_{L}}$$
(EQ. 2)

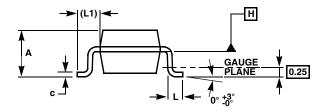
where:

- T<sub>MAX</sub> = Maximum ambient temperature
- $\theta_{JA}$  = Thermal resistance of the package
- PD<sub>MAX</sub> = Maximum power dissipation of 1 amplifier
- V<sub>S</sub> = Supply voltage (Magnitude of V<sub>+</sub> and V<sub>-</sub>)
- I<sub>MAX</sub> = Maximum supply current of 1 amplifier
- V<sub>OUTMAX</sub> = Maximum output voltage swing of the application
- R<sub>L</sub> = Load resistance

# SOT-23 Package Family







#### **MDP0038**

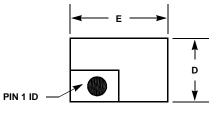
SOT-23 PACKAGE FAMILY

	MILLIN					
SYMBOL	SOT23-5	SOT23-6	TOLERANCE			
А	1.45	1.45	MAX			
A1	0.10	0.10	±0.05			
A2	1.14	1.14	±0.15			
b	0.40	0.40	±0.05			
С	0.14	0.14	±0.06			
D	2.90	2.90	Basic			
E	2.80	2.80	Basic			
E1	1.60	1.60	Basic			
е	0.95	0.95	Basic			
e1	1.90	1.90	Basic			
L	0.45	0.45	±0.10			
L1	0.60	0.60	Reference			
N	5	6	Reference			
Rev. F 2/07						

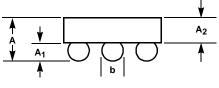
#### NOTES:

- 1. Plastic or metal protrusions of 0.25mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25mm maximum per side are not included.
- 3. This dimension is measured at Datum Plane "H".
- 4. Dimensioning and tolerancing per ASME Y14.5M-1994.
- 5. Index area Pin #1 I.D. will be located within the indicated zone (SOT23-6 only).
- 6. SOT23-5 version has no center lead (shown as a dashed line).

# Wafer Level Chip Scale Package (WLCSP)







#### SIDE VIEW

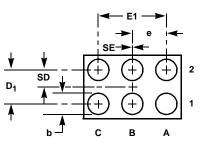


#### 3x2 ARRAY 6 BALL WAFER LEVEL CHIP SCALE PACKAGE

SYMBOL	MILLIMETERS
A	0.51 Min, 0.55 Max
A <sub>1</sub>	0.225 ±0.015
A <sub>2</sub>	0.305 ±0.013
b	Ф0.323 ±0.025
D	0.955 ±0.020
D <sub>1</sub>	0.50 BASIC
E	1.455 ±0.020
E <sub>1</sub>	1.00 BASIC
e	0.50 BASIC
SD	0.25 BASIC
SE	0.00 BASIC

NOTES:

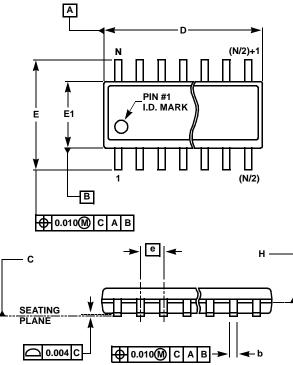
1. All dimensions are in millimeters.

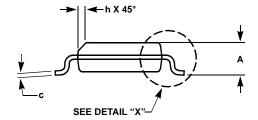


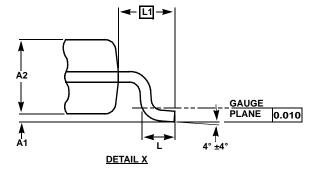
BOTTOM VIEW

Rev. 3 03/08

# Small Outline Package Family (SO)







## MDP0027

SMALL OUTLINE PACKAGE FAMILY (SO)

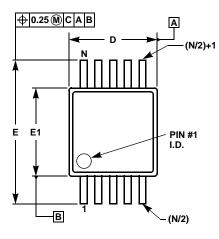
	INCHES								
SYMBOL	SO-8	SO-14	SO16 (0.150")	SO16 (0.300") (SOL-16)	SO20 (SOL-20)	SO24 (SOL-24)	SO28 (SOL-28)	TOLERANCE	NOTES
А	0.068	0.068	0.068	0.104	0.104	0.104	0.104	MAX	-
A1	0.006	0.006	0.006	0.007	0.007	0.007	0.007	±0.003	-
A2	0.057	0.057	0.057	0.092	0.092	0.092	0.092	±0.002	-
b	0.017	0.017	0.017	0.017	0.017	0.017	0.017	±0.003	-
С	0.009	0.009	0.009	0.011	0.011	0.011	0.011	±0.001	-
D	0.193	0.341	0.390	0.406	0.504	0.606	0.704	±0.004	1, 3
Е	0.236	0.236	0.236	0.406	0.406	0.406	0.406	±0.008	-
E1	0.154	0.154	0.154	0.295	0.295	0.295	0.295	±0.004	2, 3
е	0.050	0.050	0.050	0.050	0.050	0.050	0.050	Basic	-
L	0.025	0.025	0.025	0.030	0.030	0.030	0.030	±0.009	-
L1	0.041	0.041	0.041	0.056	0.056	0.056	0.056	Basic	-
h	0.013	0.013	0.013	0.020	0.020	0.020	0.020	Reference	-
Ν	8	14	16	16	20	24	28	Reference	-

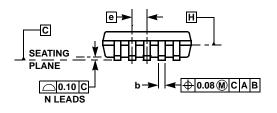
Rev. M 2/07

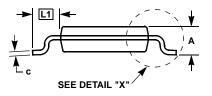
NOTES:

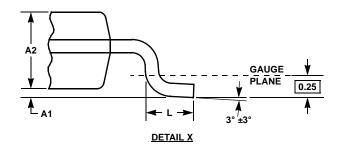
- 1. Plastic or metal protrusions of 0.006" maximum per side are not included.
- 2. Plastic interlead protrusions of 0.010" maximum per side are not included.
- 3. Dimensions "D" and "E1" are measured at Datum Plane "H".
- 4. Dimensioning and tolerancing per ASME Y14.5M-1994

# Mini SO Package Family (MSOP)









# MDP0043

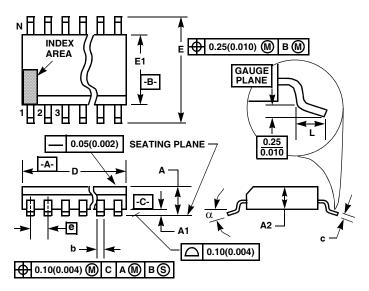
MINI SO PACKAGE FAMILY

	MILLIN	METERS					
SYMBOL	MSOP8	MSOP10	TOLERANCE	NOTES			
А	1.10	1.10	Max.	-			
A1	0.10	0.10	±0.05	-			
A2	0.86	0.86	±0.09	-			
b	0.33	0.23	+0.07/-0.08	-			
С	0.18	0.18	±0.05	-			
D	3.00	3.00	±0.10	1, 3			
Е	4.90	4.90	±0.15	-			
E1	3.00	3.00	±0.10	2, 3			
е	0.65	0.50	Basic	-			
L	0.55	0.55	±0.15	-			
L1	0.95	0.95	Basic	-			
Ν	8	10	Reference	-			
Rev. D 2/07							

NOTES:

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25mm maximum per side are not included.
- 3. Dimensions "D" and "E1" are measured at Datum Plane "H".
- 4. Dimensioning and tolerancing per ASME Y14.5M-1994.

# Thin Shrink Small Outline Plastic Packages (TSSOP)



#### NOTES:

- 1. These package dimensions are within allowable dimensions of JEDEC MO-153-AC, Issue E.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- Dimension "E1" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.15mm (0.006 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- 9. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall be 0.08mm (0.003 inch) total in excess of "b" dimension at maximum material condition. Minimum space between protrusion and adjacent lead is 0.07mm (0.0027 inch).
- 10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact. (Angles in degrees)

#### M14.173

14 LEAD THIN SHRINK SMALL OUTLINE PLASTIC PACKAGE

	INCHES		MILLIN		
SYMBOL	MIN	MAX	MIN	MAX	NOTES
A	-	0.047	-	1.20	-
A1	0.002	0.006	0.05	0.15	-
A2	0.031	0.041	0.80	1.05	-
b	0.0075	0.0118	0.19	0.30	9
С	0.0035	0.0079	0.09	0.20	-
D	0.195	0.199	4.95	5.05	3
E1	0.169	0.177	4.30	4.50	4
е	0.026	BSC	0.65 BSC		-
E	0.246	0.256	6.25	6.50	-
L	0.0177	0.0295	0.45	0.75	6
Ν	14		1	4	7
α	0 <sup>0</sup>	8 <sup>0</sup>	0 <sup>0</sup>	8 <sup>0</sup>	-

Rev. 2 4/06

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